UNISONIC TECHNOLOGIES CO., LTD

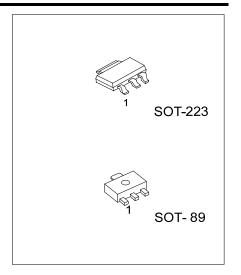
UD2195 Preliminary

NPN SILICON TRANSISTOR

NPN EPITAXIAL PLANAR TRANSISTOR

DESCRIPTION

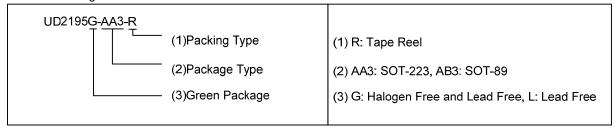
The UTC UD2195 is designed for use in general purpose amplifier and low speed switching application.



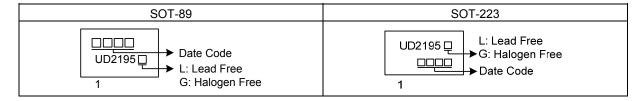
ORDERING INFORMATION

Ordering Number		Dooksans	Pin Assignment			Doolsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UD2195L-AA3-R	UD2195G-AA3-R	SOT-223	В	С	E	Tape Reel	
UD2195L-AB3-R	UD2195G-AB3-R	SOT-89	В	С	Е	Tape Reel	

E: Emitter Pin Assignment: B: Base C: Collector Note:

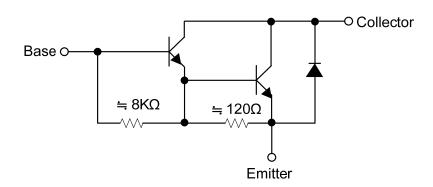


MARKING



Canny Filying 1688.com www.unisonic.com.tw 1 of 4 QW-R208-043.b

EQUIVALENT CIRCUIT





ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Base Voltage		V _{CBO}	130	V	
Collector-Emitter Voltage		V _{CEO}	120	V	
Emitter-Base Voltage		V _{EBO}	5	V	
Collector Current	DC	Ic	4	^	
	Pulse(Note 2)	IC IC	6	Α	
Collector Dissipation	SOT-223	Pc	1	W	
Collector Dissipation	SOT-89	T C	0.6	W	
unction Temperature		TJ	+150	°C	
Storage Temperature		T _{STG}	-55 ~ + 150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL CHARACTERISTICS

PARAMETER		SYMBOL	RATINGS	UNIT	
Lunction to Ambient	SOT-223	0	125	°C/W	
Junction to Ambient	SOT-89	ӨЈА	208	°C/W	

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Collector-Base Breakdown Voltage	BV_CBO	I _C =100μA, I _E =0	130			V	
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =1mA, I _B =0	120			V	
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	V_{CE} =4V, I_{C} =2A			2.8	V	
Collector Cutoff Current	I _{CBO}	V _{CB} =100V, I _E =0			1	mA	
Collector Cutoff Current	I _{CEO}	V _{CE} =50V, I _B =0			2	mA	
Emitter Cutoff Current	I _{EBO}	V_{EB} =5V, I_C =0			2	mA	
ON CHARACTERISTICS							
DC Current Gain (Note)	LIFF	V _{CE} =4V, I _C =1A	1000				
Do danent dam (Note)		V _{CE} =4V, I _C =2A	500				
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	I _C =2A, I _B =2mA			2	V	
SMALL-SIGNAL CHARACTERISTICS							
Output Capacitance	C_ob	V _{CB} =10V, I _E =0A, f=1MHz			200	pF	

Note: Pulse test: Pulse Width \leq 380 μ s, Duty Cycle \leq 2%



^{2.} Pulse test: Pulse Width ≦ 350µs, Duty Cycle ≦ 2%.

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